NSN 5961-01-005-6609

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-005-6609

Inclosure Material: Metal **Overall Length:** 0.295 inches **Terminal Length:** 1.500 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.440 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 breakdown voltage, collector-to-base, emitter open and 120.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 12.5 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Thread Series Designator:** Unf

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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NSN 5961-01-005-6609

Transistor - Page 2 of 2



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